

Description

The ZHT431 is a three terminal adjustable shunt regulator offering excellent temperature stability and output current handling capability up to 100mA. The device offers extended operating temperature range working from -55 to +125°C.

The output voltage may be set to any chosen voltage between 2.5 and 20 volts by selection of two external divider resistors.

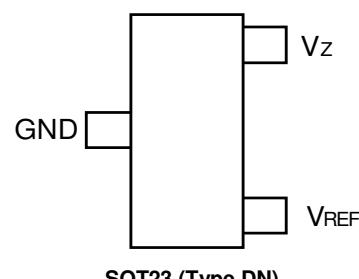
The devices can be used as a replacement for zener diodes in many applications requiring an improvement in zener performance.

Features

- Surface Mount SOT23 (Type DN) Package
- 0.5%, 1% and 2% Tolerance
- Maximum Temperature Coefficient 67ppm/°C
- Temperature Compensated for Operation Over the Full Temperature Range
- Programmable Output Voltage
- 50µA to 100mA Current Sink Capability
- Low Output Noise
- Wide Temperature Range -55 to +125°C
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. “Green” Device (Note 3)**

Pin Assignments

(Top View)



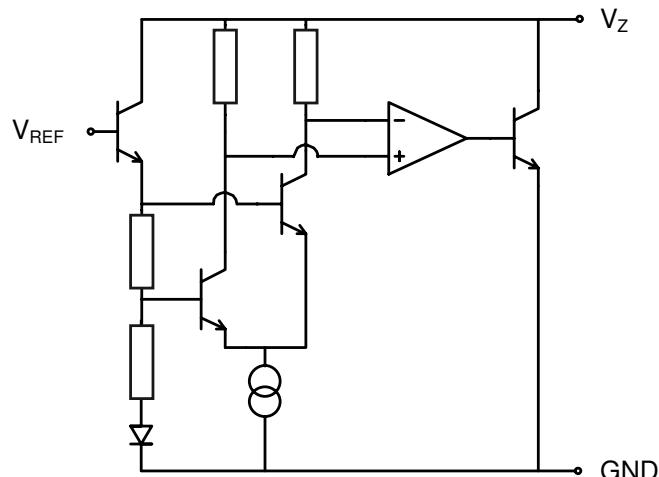
Applications

- Series and Shunt Regulator
- Voltage Monitor
- Over Voltage / Under Voltage Protection
- Switch Mode Power Supplies

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen, Antimony and Beryllium-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl), <1000ppm antimony compounds and <1000ppm Beryllium.

Typical Application Circuit



Absolute Maximum Ratings (Voltages to GND Unless Otherwise Stated.)

Parameter	Rating	Unit
Cathode Voltage (V _Z)	20	V
Cathode Current	150	mA
Operating Temperature	-55 to +125	°C
Storage Temperature	-55 to +150	°C
Power Dissipation (T _A = +25°C, T _{JMAX} = +150°C)	330	mW

Recommended Operating Conditions

Parameter	Min	Max	Unit
Cathode Voltage V _{REF}	—	20	V
Cathode Current	0.05	100	mA

Electrical Characteristics (Test conditions unless otherwise specified: T_A = +25°C.)

Symbol	VParameter	Values			Unit	Conditions
		Min.	Typ.	Max.		
V _{REF}	Reference Voltage	2%	2.45	2.50	2.55	V _L = 10mA (Fig.1), V _Z = V _{REF}
		1%	2.475	2.50	2.525	
		0.5%	2.4875	2.50	2.5125	
V _{DEV}	Deviation of Reference Input Voltage Over Temperature	—	10	30	mV	I _L = 10mA, V _Z = V _{REF} T _A = Full Range (Fig.1)
$\frac{\Delta V_{REF}}{\Delta V_Z}$	Ratio of the Change in Reference Voltage to the Change in Cathode Voltage	—	-1.85	-2.7	mV/V	V _Z from V _{REF} to 10V I _Z = 10mA (Fig.2)
		—	-1.0	-2.0	mV/V	V _Z from 10V to 20V I _Z = 10mA (Fig.2)
I _{REF}	Reference Input Current	—	0.12	1.0	μA	R ₁ = 10k, R ₂ = O/C, I _L = 10mA (Fig.2)
ΔI _{REF}	Deviation of Reference Input Current Over Temperature	—	0.04	0.2	μA	R ₁ = 10k, R ₂ = O/C, I _L = 10mA, T _A = Full Range (Fig.2)
I _{ZMIN}	Minimum Cathode Current for Regulation	—	35	50	μA	V _Z = V _{REF} (Fig.1)
I _{ZOFF}	Off-state Current	—	—	0.1	μA	V _Z = 20V, V _{REF} = 0V (Fig.3)
R _Z	Dynamic Output Impedance	—	—	0.75	V	V _Z = V _{REF} (Fig.1), f = 0Hz, I _C = 1mA to 100mA

Deviation of reference input voltage, V_{DEV}, is defined as the maximum variation of the reference input voltage over the full temperature range.

The average temperature coefficient of the reference input voltage, V_{REF} is defined as:

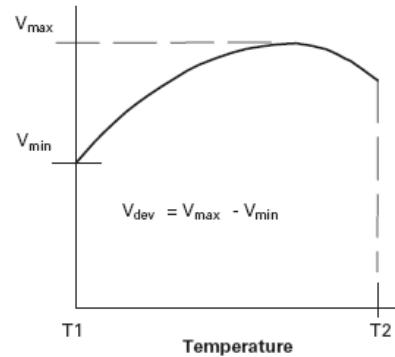
$$V_{REF} \left(\frac{\text{ppm}}{^{\circ}\text{C}} \right) = \frac{V_{DEV} \times 1000000}{V_{REF} (T_1 - T_2)}$$

The dynamic output impedance, R_Z, is defined as:

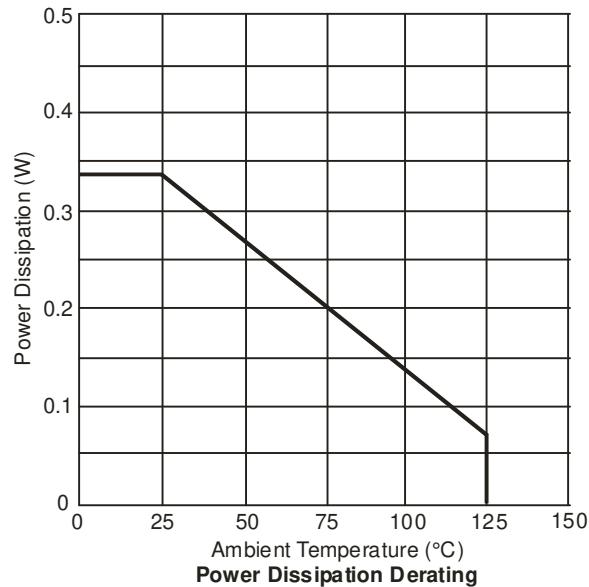
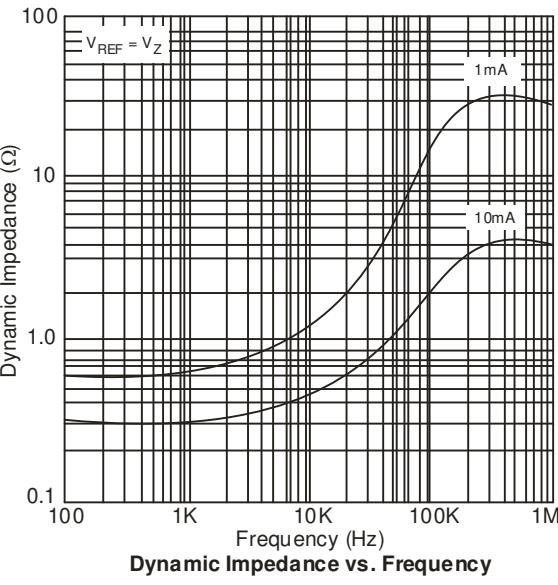
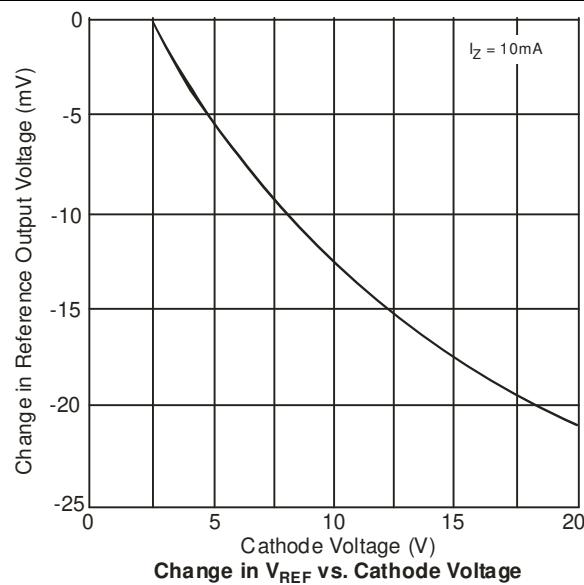
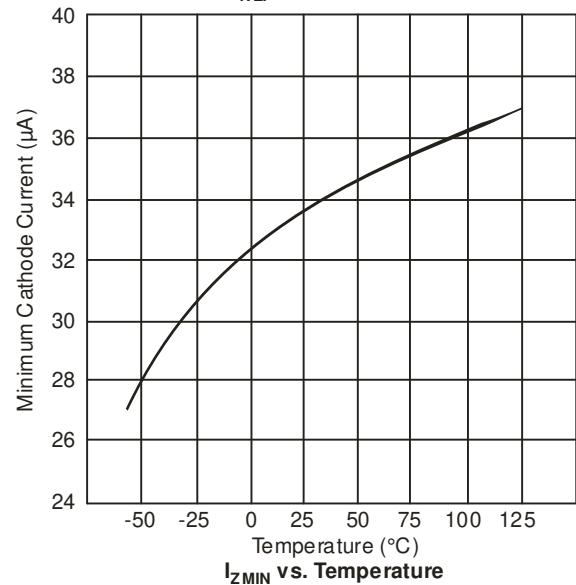
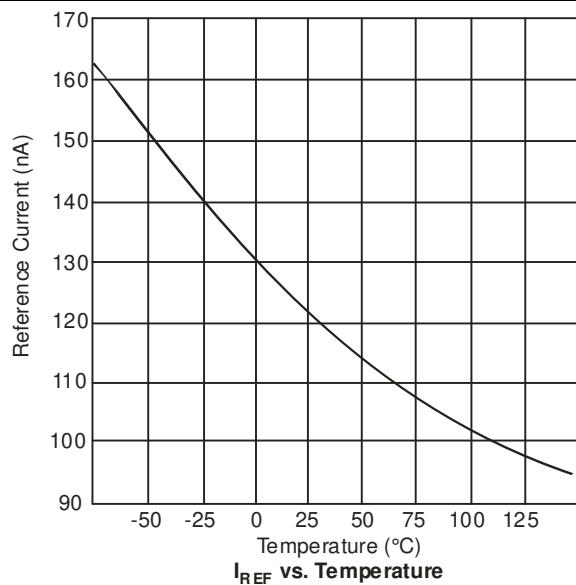
$$R_Z = \frac{\Delta V_Z}{\Delta I_Z}$$

When the device is programmed with two external resistors, R₁ and R₂, (Fig. 2), the dynamic output impedance of the overall circuit, R', is defined as:

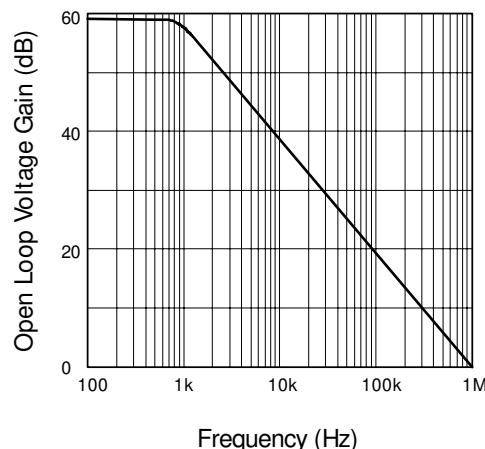
$$R' = R_Z \left(1 + \frac{R_1}{R_2} \right)$$



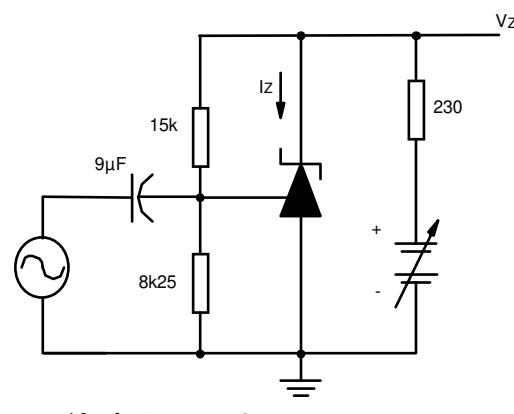
Typical Operating Conditions



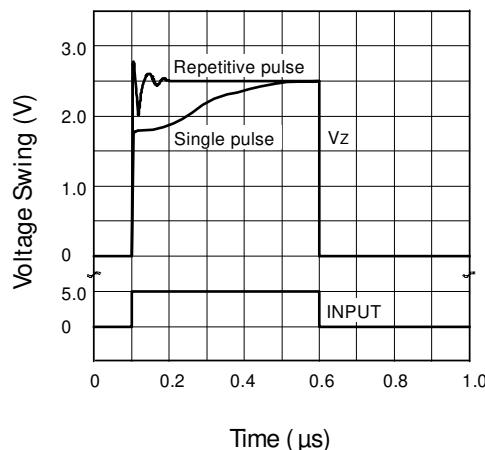
Typical Operating Conditions (Cont.)



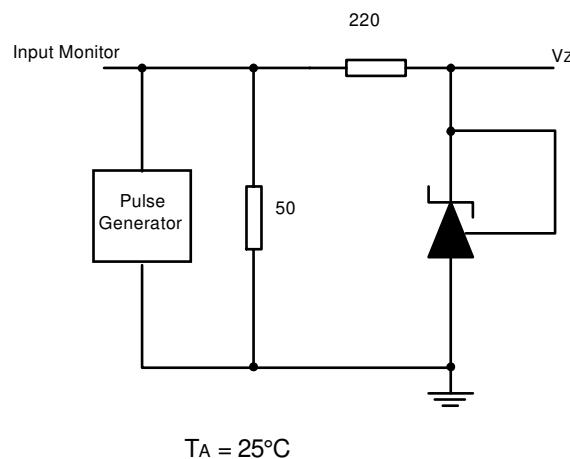
Gain v Frequency



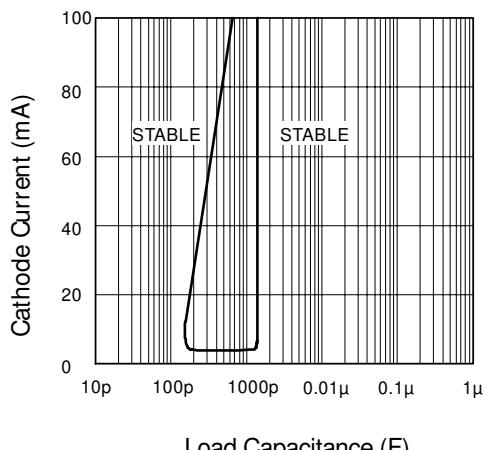
Test Circuit for Open Loop Voltage Gain



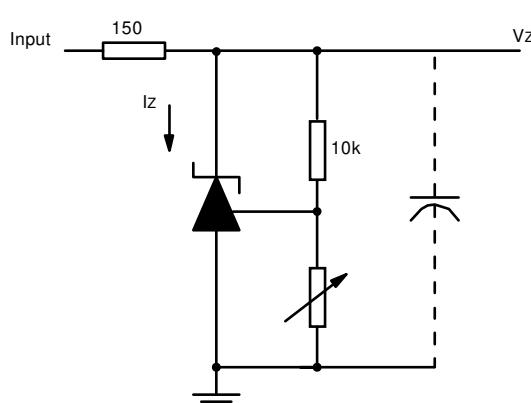
Pulse Response



Test Circuit for Pulse Response



Stability Boundary Conditions



$V_{\text{REF}} < V_Z < 20\text{V}$, $I_Z = 10\text{mA}$, $T_A = 25^\circ\text{C}$

Test Circuit for Stability Boundary Conditions

DC Test Circuits

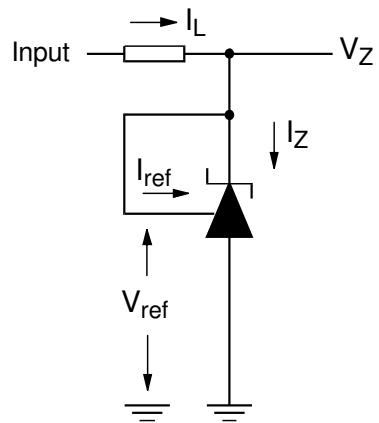


Fig 1 - Test circuit for $V_Z = V_{ref}$

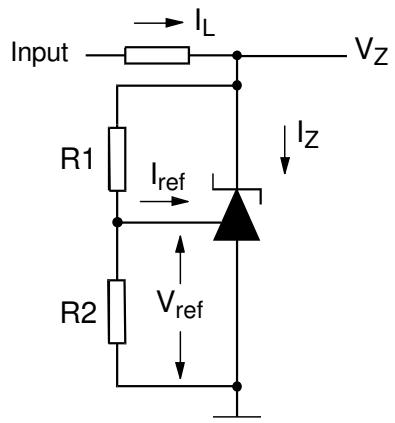


Fig 2 - Test circuit for $V_Z > V_{ref}$

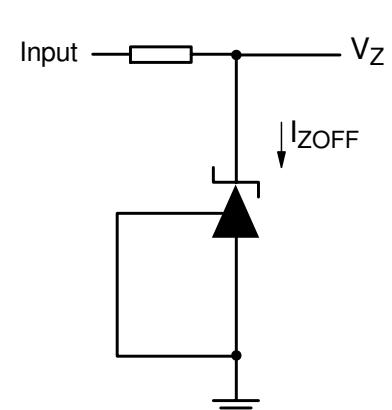
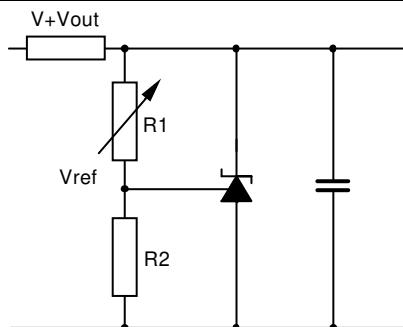


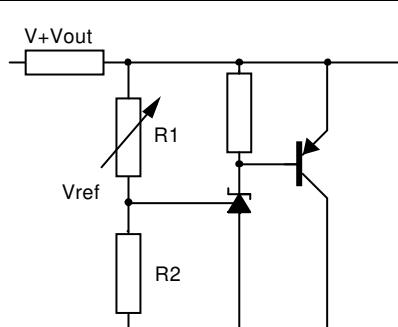
Fig 3 - Test circuit for
Off state current[†]

Application Circuits



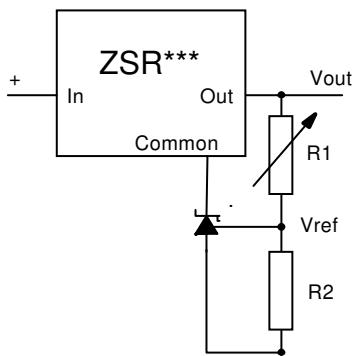
$$V_{out} = \left(1 + \frac{R_1}{R_2} \right) V_{ref}$$

Shunt regulator



$$V_{out} = \left(1 + \frac{R_1}{R_2} \right) V_{ref}$$

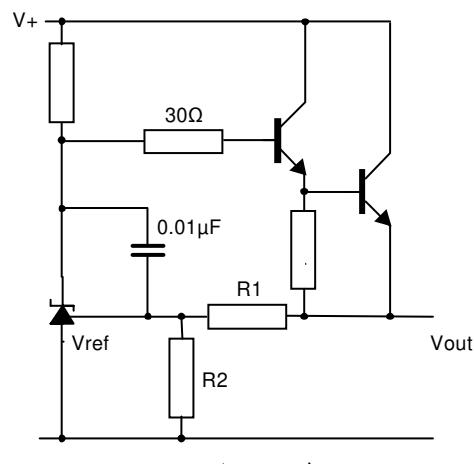
Higher current shunt regulator



$$V_{out \text{ MIN}} = V_{ref} + V_{reg}$$

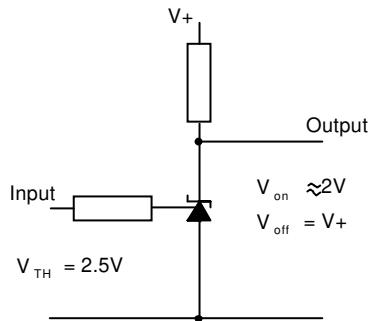
$$V_{out} = \left(1 + \frac{R_1}{R_2} \right) V_{ref}$$

Output control of a three terminal fixed regulator

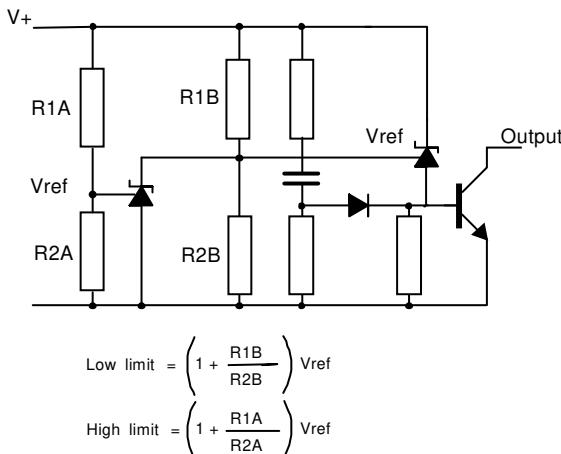


$$V_{out} = \left(1 + \frac{R_1}{R_2} \right) V_{ref}$$

Series regulator



Single supply comparator with temperature compensated threshold



Over voltage / under voltage protection circuit

Ordering Information



Part Number	Tolerance (%)	Package (Note 5)	Part Mark	Reel Size (inches)	Quantity per reel	Tape Width	Status (Note 4)
ZHT431F01TA	1	SOT23 (Type DN)	43C	7	3000	8mm	In Production
ZHT431F01-7	1	SOT23 (Type DN)	43C	7	3000	8mm	End of Life
ZHT431FMTA	0.5	SOT23 (Type DN)	43P	7	3000	8mm	In Production
ZHT431F02TA	2	SOT23 (Type DN)	43D	7	3000	8mm	In Production

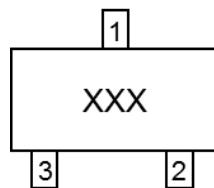
Notes: 4. ZHT431F01-7 is End of Life without any alternative.

5. For packaging details, go to our website at: <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

SOT23 (Type DN)

(Top View)

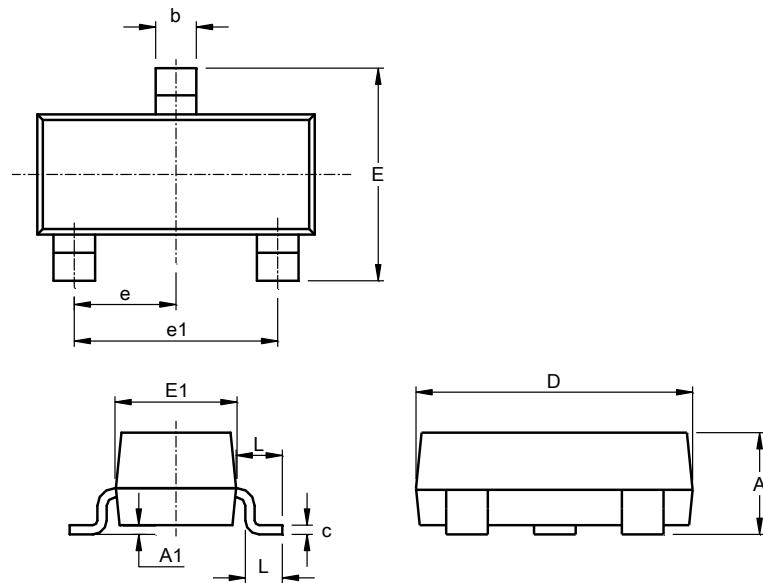


XXX : Part Mark

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for latest version.

(1) Package Type: SOT23 (Type DN)

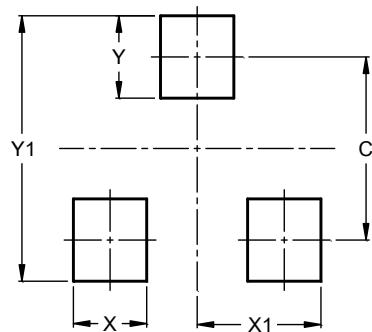


SOT23 (Type DN)			
Dim	Min	Max	Typ
A	0.89	1.12	1.00
A1	0.01	0.10	0.05
b	0.30	0.51	0.45
c	0.08	0.20	0.10
D	2.80	3.04	3.00
E	2.10	2.64	2.42
E1	1.20	1.40	1.37
e	0.95 REF		
e1	1.90 REF		
L	0.25	0.60	0.30
L1	0.45	0.62	0.54
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for latest version.

(1) Package Type: SOT23 (Type DN)



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

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